# National Semiconductor

# DM7450 Expandable Dual 2-Wide 2-Input AND-OR-INVERT Gate

### **General Description**

This device contains two independent combinations of gates, each of which perform the logic AND-OR-INVERT function. One set of gates has an expander node.

## **Connection Diagram**



TL/F/9778-1

Order Number DM7450N See NS Package Number N14A

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#### Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	7V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM74	0°C to +70°C
Storage Temperature Range	-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

### **Recommended Operating Conditions**

Symbol	Parameter	DM7450			Units
		Min	Nom	Max	onito
V <sub>CC</sub>	Supply Voltage	4.75	5	5.25	V
V <sub>IH</sub>	High Level Input Voltage	2			V
VIL	Low Level Input Voltage			0.8	V
ЮН	High Level Output Current			-0.4	mA
loL	Low Level Output Current			16	mA
TA	Free Air Operating Temperature	0		70	°C

#### **Electrical Characteristics**

Over recommended operating free air temperature range (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min$ , $I_I = -12 \text{ mA}$			-1.5	v
V <sub>OH</sub>	High Level Output Voltage	$V_{CC} = Min, I_{OH} = -400 \ \mu A$ $V_{IL} = Max$	2.4	3.4		ν
V <sub>OL</sub>	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Max$		0.2	0.4	v
կ	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$			1	mA
١ <sub>X</sub>	Expander Current	$\begin{array}{l} V1 = 0.4V, I_{OL} = 16 \text{ mA} \\ V_{CC} = \text{Min}, T_{A} = \text{Min} \end{array}$			3.1	mA
IIH	High Level Input Current	$V_{CC} = Max, V_1 = 2.4V$			40	μΑ
կլ	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$			-1.6	mA
los	Short Circuit Output Current	V <sub>CC</sub> = Max (Note 2)	- 18		-57	mA
ICCH	Supply Current with Outputs High	V <sub>CC</sub> = Max			8	mA
ICCL	Supply Current with Outputs Low	V <sub>CC</sub> = Max			14	mA
V <sub>BE(Q)</sub>	Base-Emitter Voltage of Output Transistor Q	I1 = 0.62  mA $I_{OL} = 16 \text{ mA}$ $R_1 = 0\Omega$			1.0	v

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Symbol	Parameter	Conditions	Min	Max	Units
t <sub>PLH</sub>	Propagation Delay Time Low to High Level Output	$C_L = 15  pF$ $R_L = 400 \Omega$		22	ns
tPHL	Propagation Delay Time High to Low Level Output			15	ns
	e at $V_{CC} = 5V$ , $T_A = 25^{\circ}C$ .				
Note 2: Not more that	n one output should be shorted at a time.				
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	<i>,</i>				